

OSFP-800G-XDR8-IB

800G OSFP XDR8 InfiniBand Transceiver

Hot Pluggable, +3.3V, Dual MPO, 1310nm, SMF, 2km, Commercial Temperature

FEATURES

- Hot-pluggable OSFP form factor
- EML transmitter and PIN PD receiver
- Support 850Gb/s aggregate bit rate
- Support both Ethernet and InfiniBand NDR
- Compliant with IEEE 802.3cu-2021: 8x100GBASE-DR optical interface
- Compliant with IEEE 802.3ck-2022: 8x100GAUI-1 C2M electrical interface
- Compliant with InfiniBand Trade Association (IBTA) Specification 1.6- InfiniBand NDR electrical and optical interface
- Compliant with OSFP MSA Specification Rev 5.0
- Type 2 housing with Dual MPO-12/APC receptacle Compliant with CMIS Rev 5.0
- Two wire serial Interface with digital diagnostic monitoring
- Complies with EU Directive 2011/65/EU (RoHS compliant)
- Class 1 Laser
- Commercial Operating Temperature Range: 0 to 70°C

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Min.	Max.	Unit
Storage Temperature	T _s	-40	85	°C
Supply Voltage	V _{CC}	-0.5	3.6	V
Relative Humidity (non-condensing)	RH	5	95	%
Data Input Voltage Differential	I _V DIP-V _{DIN} I	-	1	V
Control Input Voltage	V _I	-0.3	V _{CC} +0.5	V
Control Output Current	I _O	-20	20	mA

RECOMMENDED OPERATING ENVIRONMENT

Parameter	Symbol	Min.	Typical	Max.	Unit	Note
Operating Case Temperature	T _{OPR}	0	-	70	°C	
Power Supply Voltage	V _{CC}	3.135	3.3	3.465	V	
Instantaneous peak current at hot plug	I _{CC_IP}	-	-	6600	mA	
Sustained peak current at hot plug	I _{CC_SP}	-	-	5494.5	mA	
Maximum Power Dissipation	P _D	-	-	16.5	W	
Maximum Power Dissipation, Low Power Mode	P _{DLP}	-	-	2	W	
Signalling Speed per Lane	DRL	-	53.125	-	GBd	
Control Input Voltage High	V _{IH}	V _{CC} *0.7	-	V _{CC} +0.3	V	
Control Input Voltage Low	V _{IL}	-0.3	-	V _{CC} *0.3	V	
Two Wire Serial Interface Clock Rate	-	-	-	400	kHz	
Power Supply Noise 1 kHz - 1 MHz (p-p)	-	-	-	66	mVpp	
Operating Distance	-	2	-	2000	m	

OPTICAL PARAMETERS

Parameter	Symbol	Min	Typical	Max	Unit	Notes
TRANSMITTER						
Wavelength	λ_c	1304.5	1311	1317.5	nm	
Side Mode Suppression Ratio	SMSR	30	-	-	dB	
Average Launch Power, each lane	AOP _L	-2.9	-	4.0	dBm	1
Outer Optical Modulation Amplitude (OMA _{outer}), each Lane	T _{OMA}	-0.8	-	4.2	dBm	
Launch power in OMA _{outer} minus TDECQ, each lane for extinction ratio ≥ 5 dB for extinction ratio < 5 dB	T _{OMA-TDECQ}	-2.2 -1.9	-	-	dBm	
Transmitter and Dispersion Eye Closure for PAM4 (TDECQ), each lane	TDECQ	-	-	3.4	dB	
TDECQ – 10log10(Ceq), each lane	Ceq	-	-	3.4	dB	
Average Launch Power of OFF Transmitter, each lane	T _{OFF}	-	-	-15	dBm	
Extinction Ratio	ER	3.5	-	-	dB	
Transmitter transition time	Tr			17	ps	
RIN _{15.5OMA}	RIN	-	-	-136	dB/H z	
Optical return loss tolerance	ORL	-	-	15.5	dB	
Transmitter Reflectance	T _R	-	-	-26	dB	2
RECEIVER						
Wavelength	λ_{c0}	1304.5	1311	1317.5	nm	
Damage Threshold, each Lane	AOP _D	5	-	-	dBm	
Average Receive Power, each Lane	AOP _R	-5.9	-	4	dBm	
Receive Power (OMA _{outer}), each Lane	OMA _R	-	-	4.2	dBm	
Receiver Reflectance	RR	-	-	-26	dB	
Receiver Sensitivity (OMA _{outer}), each Lane	S _{OMA}	-	-	Max (-3.9, SECQ–5.3)	dBm	3
Stressed Receiver Sensitivity (OMA _{outer}), each Lane	SRS	-	-	-1.9	dBm	4
CONDITIONS OF STRESSED RECEIVER SENSITIVITY TEST						
Stressed eye closure for PAM4 (SECQ), lane under test	SECQ	-	3.4	-	dB	
SECQ – 10log10(Ceq), lane under test	Ceq	-	-	3.4	dB	

Note:

1. Average launch power, each lane (min) is informative and not the principal indicator of signal strength
2. Transmitter reflectance is defined looking into the transmitter.
3. Receiver sensitivity (OMA_{outer}), each lane (max) is informative and is defined for a transmitter with a value of SECQ up to 3.4 dB.
4. Measured with conformance test signal at TP3 for the BER = 2.4×10^{-4}

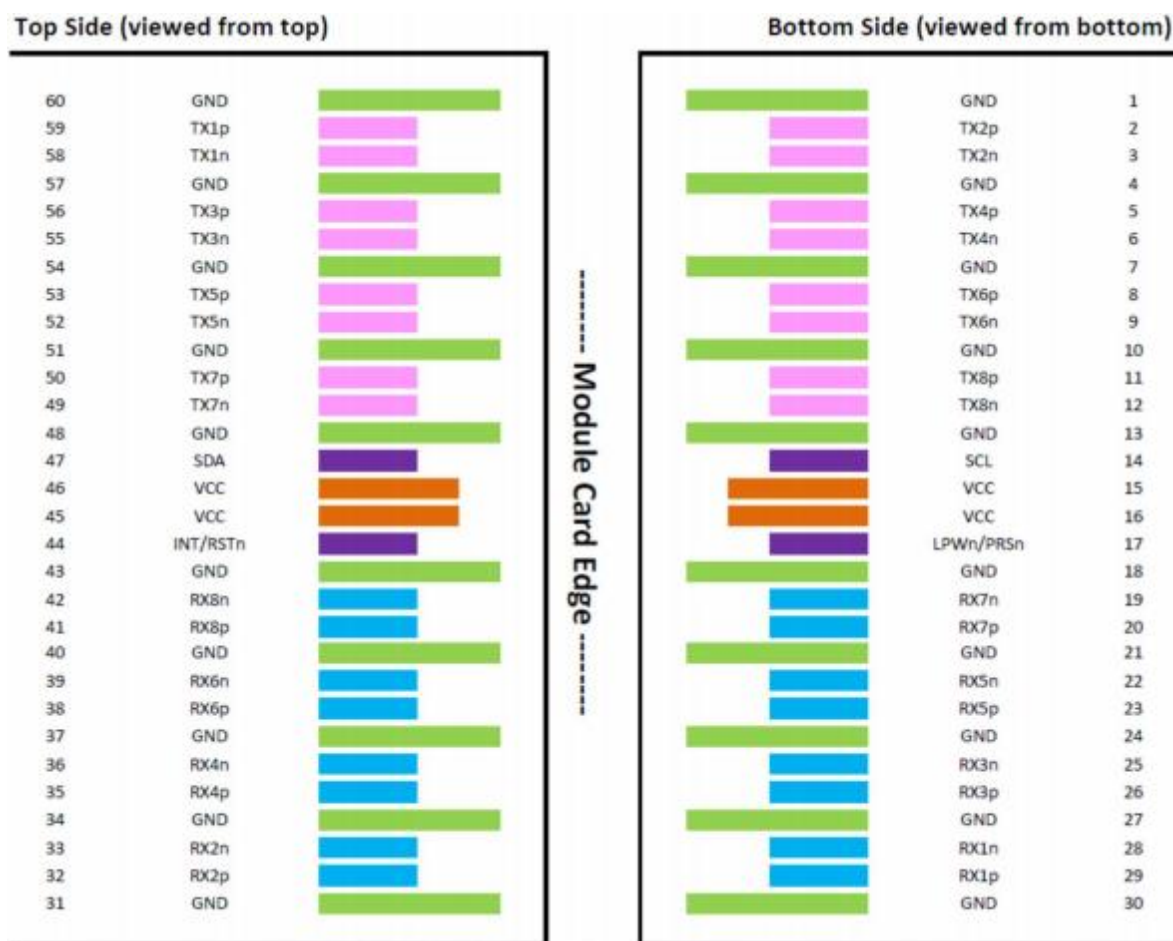
ELECTRICAL CHARACTERISTICS (High Speed Signal - compliant with IEEE802.3ck C2M)

Parameter	Symbol	Min	Typical	Max	Unit	Note
TRANSMITTER (Module Input, TP1)						
Differential pk-pk input Voltage tolerance (TP1a)	-	750	-	-	mV	
Peak-to-peak AC common-mode voltage tolerance Low-frequency, VCMLF Full-band, VCMFB	-	-	-	32 80	mV	
Differential-mode to common-mode return loss	RL _{cd}	802.3ck 120G-2			dB	
Effective return loss	ERL	8.5	-	-	dB	
Differential termination mismatch	-	-	-	10	%	
Single-ended voltage tolerance range	-	-0.4	-	3.3	V	
DC common-mode voltage tolerance	-	-0.35	-	2.85	V	
RECEIVER (Module Output, TP4)						
Peak-to-peak AC common-mode voltage Low-frequency, VCMLF Full-band, VCMFB	-	-	-	32 80	mV	
Differential peak-to-peak output voltage Short mode Long mode	-	-	-	600 845	mV	
Eye height	EH	15	-	-	mV	
Vertical eye closure	VEC	-	-	12	dB	
Common-mode to differential-mode return loss	RL _{Dc}	802.3ck 120G-1			dB	
Effective return loss	ERL	8.5	-	-	dB	
Differential termination mismatch	-	-	-	10	%	
Transition time	-	8.5	-	-	ps	
DC common-mode voltage tolerance	-	-0.35	-	2.85	V	

ELECTRICAL CHARACTERISTICS (Low Speed Control and Sense Signals)

Parameter	Symbol	Min.	Max.	Unit
Module output SCL and SDA	V _{OL}	0	0.4	V
Module Input SCL and SDA	V _{IL}	-0.3	V _{CC} *0.3	V
	V _{IH}	V _{CC} *0.7	V _{CC} +0.5	V
InitMode, ResetL and ModSelL	V _{IL}	-0.3	0.8	V
	V _{IH}	2	V _{CC} +0.3	V
IntL	V _{OL}	0	0.4	V
	V _{OH}	V _{CC} -0.5	V _{CC} +0.3	V

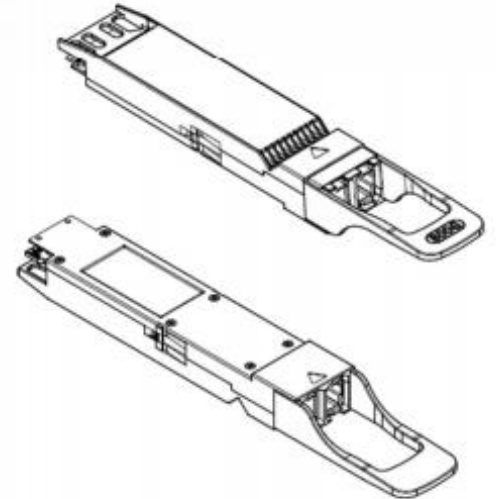
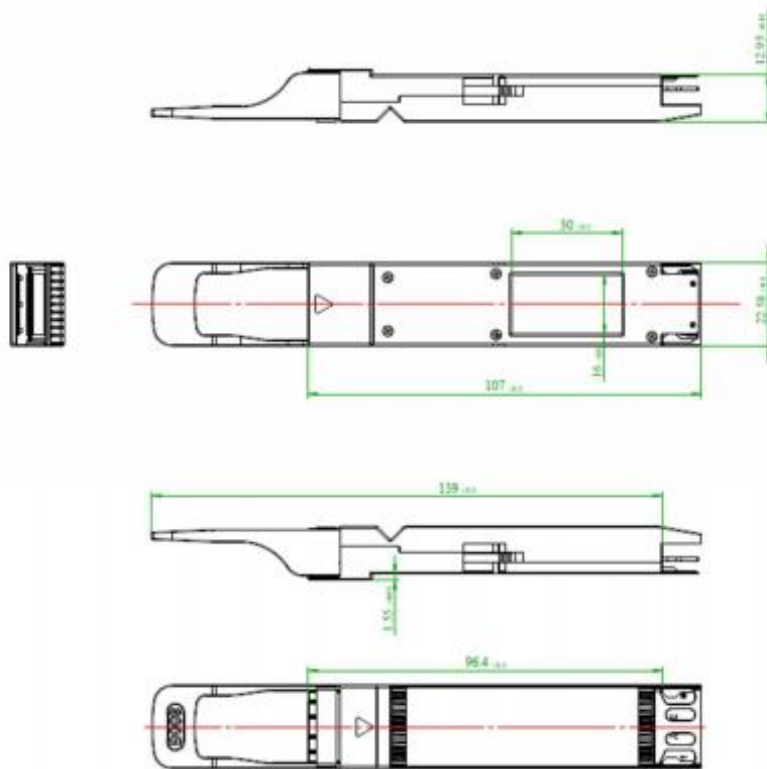
PIN ASSIGNMENT



Pinout definitions of OSFP module inputs/outputs

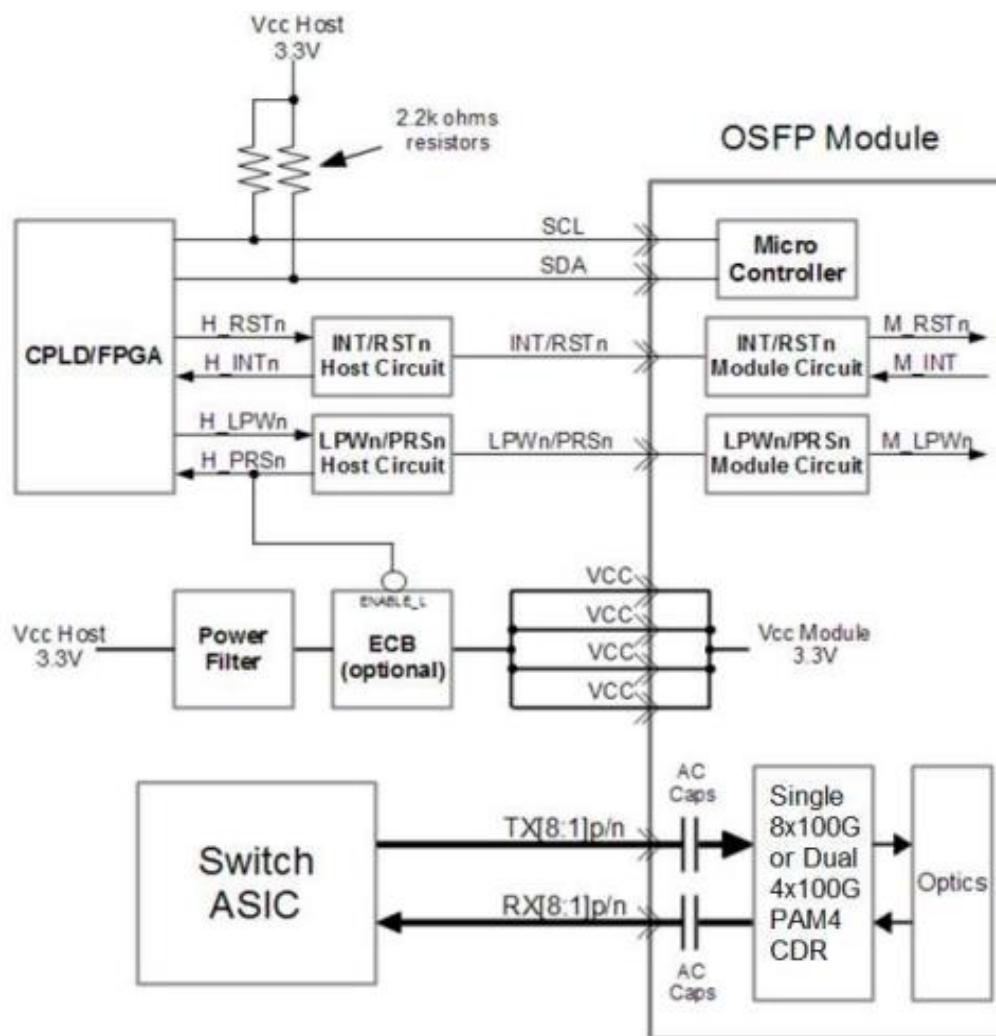
Pin	Logic	Symbol	Description	Pin	Logic	Symbol	Description
1		GND	Ground	31		GND	Ground
2	CML-I	TX2p	Transmitter Data Non-Inverted	32	CML-O	RX2p	Receiver Data Non-Inverted
3	CML-I	TX2n	Transmitter Data Inverted	33	CML-O	RX2n	Receiver Data Inverted
4		GND	Ground	34		GND	Ground
5	CML-I	TX4p	Transmitter Data Non-Inverted	35	CML-O	RX4p	Receiver Data Non-Inverted
6	CML-I	TX4n	Transmitter Data Inverted	36	CML-O	RX4n	Receiver Data Inverted
7		GND	Ground	37		GND	Ground
8	CML-I	TX6p	Transmitter Data Non-Inverted	38	CML-O	RX6p	Receiver Data Non-Inverted
9	CML-I	TX6n	Transmitter Data Inverted	39	CML-O	RX6n	Receiver Data Inverted
10		GND	Ground	40		GND	Ground
11	CML-I	TX8p	Transmitter Data Non-Inverted	41	CML-O	RX8p	Receiver Data Non-Inverted
12	CML-I	TX8n	Transmitter Data Inverted	42	CML-O	RX8n	Receiver Data Inverted
13		GND	Ground	43		GND	Ground
14	LVC MOS-I/O	SCL	2-wire Serial interface clock	44	Multi-Level	INT/RSTn	Module Interrupt / Module Reset
15		VCC	+3.3V Power	45		VCC	+3.3V Power
16		VCC	+3.3V Power	46		VCC	+3.3V Power
17	Multi-Level	LPWn/PR Sn	Low-Power Mode / Module Present	47	LVC MOS-I/O	SDA	2-wire Serial interface data
18		GND	Ground	48		GND	Ground
19	CML-O	RX7n	Receiver Data Inverted	49	CML-I	TX7n	Transmitter Data Inverted
20	CML-O	RX7p	Receiver Data Non-Inverted	50	CML-I	TX7p	Transmitter Data Non-Inverted
21		GND	Ground	51		GND	Ground
22	CML-O	RX5n	Receiver Data Inverted	52	CML-I	TX5n	Transmitter Data Inverted
23	CML-O	RX5p	Receiver Data Non-Inverted	53	CML-I	TX5p	Transmitter Data Non-Inverted
24		GND	Ground	54		GND	Ground
25	CML-O	RX3n	Receiver Data Inverted	55	CML-I	TX3n	Transmitter Data Inverted
26	CML-O	RX3p	Receiver Data Non-Inverted	56	CML-I	TX3p	Transmitter Data Non-Inverted
27		GND	Ground	57		GND	Ground
28	CML-O	RX1n	Receiver Data Inverted	58	CML-I	TX1n	Transmitter Data Inverted
29	CML-O	RX1p	Receiver Data Non-Inverted	59	CML-I	TX1p	Transmitter Data Non-Inverted
30		GND	Ground	60		GND	Ground

MECHANICAL DIMENSIONS (UNIT: mm)



OSFP -DR8 -Dual MPO

RECOMMENDED HOST BOARD



Recommended OSFP Host Board Schematic

DIGITAL DIAGNOSTICS

Parameter	Range	Accuracy	Unit	Calibration
Temperature	0 to 70	±3	°C	Internal
Voltage	0 to Vcc	0.1	V	Internal
Tx Bias Current (Each Lane)	0 to 100	10%	mA	Internal
Tx Output Power (Each Lane)	-2.9 to +4	±3	dB	Internal
Rx Receive Power (Each Lane)	-5.9 to +4	±3	dB	Internal